

Voltage Detector IC Series

Counter Timer Built-in CMOS Voltage Detector IC

BU45Kxxxx, BU46Kxxxx, BU45Lxxxx, BU46Lxxxx series

General Description

ROHM's BU45xxxxx and BU46xxxxx series are highly accurate, low current consumption voltage detector IC series. Because the counter timer delay circuit is built-in, an external capacitor for the delay time setting is unnecessary. Two output types are available (Nch open drain and CMOS output) and detection voltages range from 2.3V to 4.8V in increments of 0.1V with fixed delay time of 200ms and 400ms, that may be selected according to application.

Features

VDD1O

SSOP3

GND

- . Counter Timer Built-in
- No delay time setting capacitor required
- Low current consumption
- Two output types (Nch open drain and CMOS output)
- Package SSOP3 is similar to SOT-23-3 (JEDEC)

Key Specifications

- Detection voltage: 2.3V to 4.8V (Typ.) 0.1V steps High accuracy detection voltage: ±1.0% Low current consumption: 2.3µA (Typ.) Operating temperature range: -40°C to +105°C Two internal, fixed delay time: 200ms 400ms Package SSOP3 2.92mm x 2.80mm x 1.25mm Applications Circuits using microcontrollers or logic circuits that require a reset Typical Application Circuit VDD1 O Rι Micro Micro BD46 xx x xx Rst BU45 xxxxx controller Rsт controller CL СL (Noise-filtering (Noise-filtering Capacitor) Capacitor) GND GND O (Open Drain Output Type) (CMOS Output Type) BU45xxxxx series BU46xxxxx series Connection Diagram Pin Descriptions BU45KxxxG / BU46KxxxG PIN No. Symbol Function GND VDD GND 1 GND 3 3 2 VOUT Reset Output 3 VDD Power Supply Voltage BU45LxxxG / BU46LxxxG 1 2 PIN No. Symbol Function VOUT VDD VOUT **Reset Output** 1 VOUT BU45KxxxG BU45LxxxG 2 Vdd Power Supply Voltage BU46KxxxG BU46LxxxG 3 GND GND
 - OProduct structure : Silicon monolithic integrated circuit OThis product is not designed for protection against radioactive rays.

Ordering Information

E	3 U	X	X	X	x x	>	(x - [T L
Part Numb	per	Output Typ 45 : Open I 46 : CMOS	Drain	23 :	et Voltage Valu 2.3V ↓ 0.1V ste⊨ 4.8V	Delay Time		f	Packaging and orming specificatio L : Embossed tap and reel
Package 1 Package 2 Package name K G SSOP3 (1pin GND) L G SSOP3 (3pin GND)									
	• 1. Open Dra	in Output Ty	rpe			>	0		
				Cou	inter Timer De	elay Time Set	tings		
			1-Pi	n GND			3-Pin	GND	
		20	0ms	400	Oms	200	Oms	40	0ms
	Detection Voltage	Marking	Part Number	Marking	Part Number	Marking	Part Number	Marking	Part Number
_	4.8V	bH	BU45K482	eF	BU45K484	hD 🗸	BU45L482	nB	BU45L484
-	4.7V	bG	BU45K472	eE	BU45K474	hC	BU45L472	nA	BU45L474
-	4.6V	bF	BU45K462	eD	BU45K464 BU45K454	hB	BU45L462 BU45L452	mY	BU45L464
-	4.5V 4.4V	bE bD	BU45K452 BU45K442	eC eB	BU45K444 BU45K444	hA gY	BU45L432 BU45L442	mX mW	BU45L454 BU45L444
	4.3V	bC	BU45K432	eA	BU45K434	gX	BU45L432	mT	BU45L434
_	4.2V	_	-	dY	BU45K424	gW	BU45L422	mS	BU45L424
	4.1V	bA	BU45K412	dX	BU45K414	gT	BU45L412	mR	BU45L414
	4.0V	aY	BU45K402	dW	BU45K404	gS	BU45L402	mP	BU45L404
_	3.9V	aX	BU45K392	d⊤	BU45K394	gR	BU45L392	mN	BU45L394
_	3.8V	aW	BU45K382	dS	BU45K384	gP	BU45L382	mM	BU45L384
-	3.7V	aT	BU45K372	dR	BU45K374	gN	BU45L372	mK	BU45L374
-	3.6V	-		dP	BU45K364 BU45K354	gM	BU45L362	mH	BU45L364
_	3.5V 3.4V	aR aP	BU45K352 BU45K342	dN dM	BU45K354 BU45K344	gK gH	BU45L352 BU45L342	mG mF	BU45L354 BU45L344
-	3.4V 3.3V	dr -	D045N342	dK	BU45K334	gH gG	BU45L342 BU45L332	mE	BU45L344 BU45L334
-	3.2V	aM	BU45K322	dH	BU45K324	gG gF	BU45L322	mD	BU45L324
-	3.1V	аК	BU45K312	dG	BU45K314	gE	BU45L312	mC	BU45L314
-	3.0V	aH	BU45K302		-	gD	BU45L302	mB	BU45L304
F	2.9V	X	-	-	-	gC	BU45L292	mA	BU45L294
	2.8V	aF	BU45K282	dD	BU45K284	gB	BU45L282	kY	BU45L284
	2.7V	aE	BU45K272	dC	BU45K274	gA	BU45L272	kX	BU45L274
F	2.6V		-	dB	BU45K264	fY	BU45L262	kW	BU45L264
-	2.5V	aC	BU45K252	dA	BU45K254	fX	BU45L252	kT	BU45L254
-	2.4V	-	-	cY	BU45K244	fW	BU45L242	kS	BU45L244
	2.3V	aA	BU45K232	cX	BU45K234	_	-	-	-

●Lineup - Continued

Table 2. CMOS Output Type

	Counter Timer De				lay Time Settings			
	1-Pin GND			3-Pin GND				
	20	0ms	400ms		200	Oms	40	Oms
Detection Voltage	Marking	Part Number	Marking	Part Number	Marking	Part Number	Marking	Part Number
4.8V	cW	BU46K482	fS	BU46K484	kP	BU46L482	pМ	BU46L484
4.7V	сТ	BU46K472	fR	BU46K474	kN	BU46L472	рК	BU46L474
4.6V	cS	BU46K462	fP	BU46K464	kM	BU46L462	рН	BU46L464
4.5V	cR	BU46K452	fN	BU46K454	kК	BU46L452	pG	BU46L454
4.4V	сР	BU46K442	fM	BU46K444	kH	BU46L442	рF	BU46L444
4.3V	cN	BU46K432	fK	BU46K434	kG	BU46L432	pЕ	BU46L434
4.2V	сM	BU46K422	fH	BU46K424	kF	BU46L422	рD	BU46L424
4.1V	сК	BU46K412	fG	BU46K414	kE	BU46L412	рС	BU46L414
4.0V	-	-	fF	BU46K404	kD	BU46L402	рВ	BU46L404
3.9V	cG	BU46K392	fE	BU46K394	kC	BU46L392	рА	BU46L394
3.8V	cF	BU46K382	fD	BU46K384	kВ	BU46L382	nY	BU46L384
3.7V	cE	BU46K372	fC	BU46K374	💧 kA	BU46L372	nX	BU46L374
3.6V	cD	BU46K362	fB	BU46K364	hY	BU46L362	nW	BU46L364
3.5V	сC	BU46K352	fA	BU46K354	hX 🗸	BU46L352	nT	BU45L354
3.4V	сВ	BU46K342	eY	BU46K344	hW	BU46L342	nS	BU46L344
3.3V	cA	BU46K332	eX	BU46K334	hT	BU46L332	nR	BU46L334
3.2V	bY	BU46K322	eW	BU46K324	hS	BU46L322	nP	BU46L324
3.1V	bX	BU46K312	eT	BU46K314	hR	BU46L312	nN	BU46L314
3.0V	bW	BU46K302	eS	BU46K304	hP	BU46L302	nM	BU46L304
2.9V	-	-	eR	BU46K294	hN	BU46L292	nK	BU46L294
2.8V	bS	BU46K282	eP	BU46K284	hM	BU46L282	nH	BU46L284
2.7V	bR	BU46K272	eN	BU46K274	hK	BU46L272	nG	BU46L274
2.6V	bP	BU46K262	eM	BU46K264	hH	BU46L262	nF	BU46L264
2.5V	bN	BU46K2 <mark>5</mark> 2	eK	BU46K254	hG	BU46L252	nE	BU46L254
2.4V	bM	BU46K242	eН	BU46K244	hF	BU46L242	nD	BU46L244
2.3V	bK	BU46K232	eG	BU46K234	hE	BU46L232	nC	BU46L234

• Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limit	Unit
Power Supply Volt	age	VDD-GND	-0.3 to +6.0	V
	Nch Open Drain Output	Mour	GND-0.3 to +6.0 🬰	v
Output Voltage	CMOS Output	Vout	GND-0.3 to VDD+0.3	v
Output Current		lo	70	mA
Power Dissipation	(Note1, Note2)	Pd	700	mW
Operating Temperating	ature	Topr	-40 to +105	°C
Ambient Storage T	emperature	Tstg	-55 to +125	°C

(Note 1) Use above Ta=25°C results in a 7.0mW loss per degree.

(Note 2) When mounted on ROHM standard circuit board (70mmx70mmx1.6mm, glass epoxy board).

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Electrical characteristics (Unless Otherwise Specified Ta=-40 to 105°C)

Parameter	Symbol	Condition		Limit			Unit		
	0,				Min.	Тур.	Max.		
Operating Voltage Range	Vopl	VoL≤0.4V, RL=470kΩ, Ta=25~105°C			0.6	-	6.0	v	
	VOIL	VoL≤0.4V, RL=4	70kΩ, Ta=-40	~25°C	0.9	-	6.0		
		VDD=H→L, RL=470kΩ (Note 1)			VDET(T)	VDET(T)	Vdet(T)		
				×0.99		×1.01			
			Ta=2		2.475	2.5	2.525	-	
		VDET=2.5V	Ta=-	40°C to 85°C	2.418	-	2.584		
			Ta=8	5°C to 105°C	2.404	-	2.597	-	
			Ta=2	25°C	2.970	3.0	3.030	-	
		VDET=3.0V	Ta=-	40°C to 85°C	2.901	-	3.100	-	
			Ta=8	5°C to 105°C 🖕	2.885	-	3.117	_	
Detection Voltage	VDET		Ta=2	25°C	3.267	3.3	3.333	V	
		VDET=3.3V	Ta=-	40°C to 85°C	3.191	-	3.410		
		4	Ta=8	5°C to 105°C	3.173	-	3.428		
			Ta=2	25°C	4.158	4.2	4.242		
		VDET=4.2V	Ta=-	Ta=-40°C to 85°C		-	4.341	-	
			Ta=8	Ta=85°C to 105°C		-	4.364		
			Ta=2	Ta=25°C		4.8	4.848		
		VDET=4.8V	Ta=-	Ta=- <mark>40</mark> °C to 85°C		-	4.961		
			Ta=8	Ta=85°C to 105°C		-	4.987		
Detection Voltage Temperature coefficient	Vdet/ ΔT	-40°C~105°C			-	±50	±360	ppm/°C	
		Vdd=L→H→L, RL=470kΩ		VDET(T)	VDET(T)	VDET(T)	N		
Hysteresis Voltage	ΔVdet				×0.03	×0.05	×0.08	V	
	0			Ta=25°C	120	200	280		
		CL=100pF,	BU4xxxx2G	Ta=-40°C to 85°C	95	-	460		
'High' Output		RL=100kΩ		Ta=85°C to 105°C	85	-	235		
Delay time	tPLH	(Note1,		Ta=25°C	240	400	560	ms	
		Note 2,	BU4xxxx4G	Ta=-40°C to 85°C	190	-	920	-	
		Note 3)		Ta=85°C to 105°C	170	-	470		
Circuit Current when ON	IDD1	VDD=VDET-0.2V	VDET=2.3V	~4.8V	0.60	2.30	7.00	μA	
Circuit Current when OFF	IDD2	VDD=VDET+1.0V, VDET=2.3V~4.8V		1.10	2.80	8.00	μA		
'High' Output Voltage (Pch)	🕨 Vон	VDD=5.0V, ISOURCE= 6.8mA, VDET(4.3V to 4.8V)		VDD-0.5		-	V		
(Low/Output Valtage (Nab)	11	VDD=1.2V, ISINK = 2.0mA		-	-	0.3	V		
'Low'Output Voltage (Nch)	Vol	VDD=2.4V, ISINK = 8.5mA, VDET(2.7V to 4.8V)		-	-	0.3	V		
Leak Current when OFF	Current when OFF Ileak VDD=VDS=6.0V (Note 1)			-	-	1.0	μA		

VDET(T):Standard Detection Voltage (2.3V to 4.8V, 0.1V step)

RL :Pull-up resistor to be connected between VOUT and power supply.

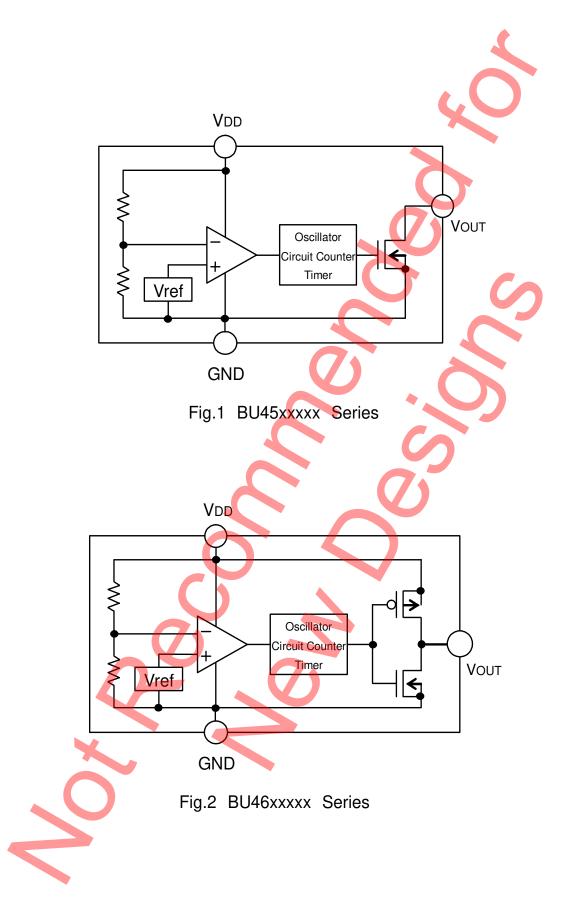
CL :Capacitor to be connected between VOUT and GND.

(Note 1) Guarantee is Ta=25°C.

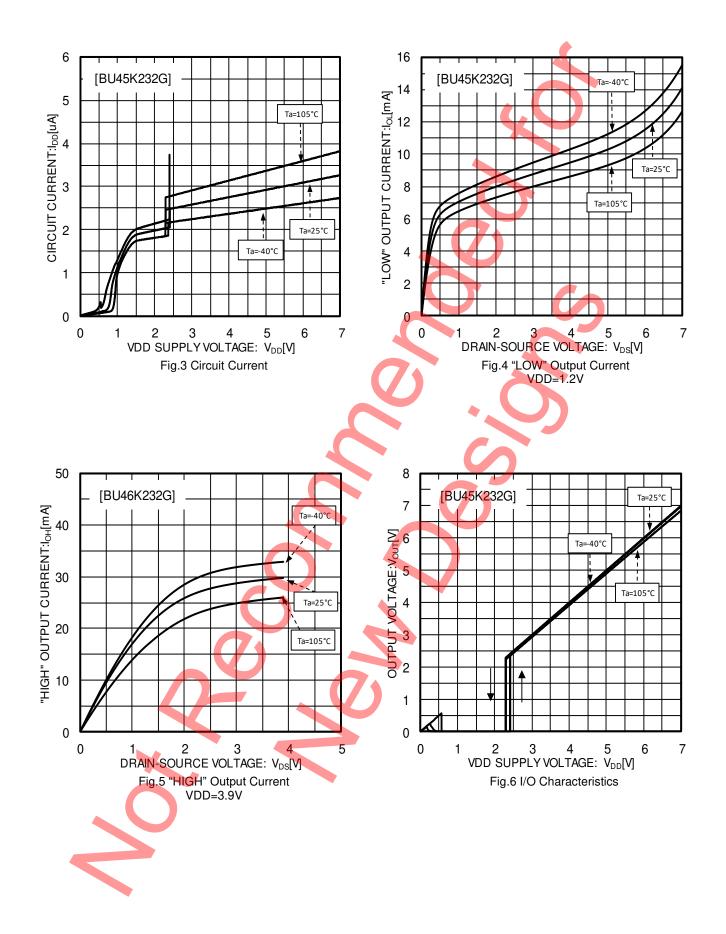
(Note 2) tPLH:VDD=(VDET(T)-0.5V) \rightarrow (VDET(T)+0.5V)

(Note 3) tPLH:VDD=Please set up the rise up time between VDD=V_{OPL} \rightarrow VDET more than 10 μ s.

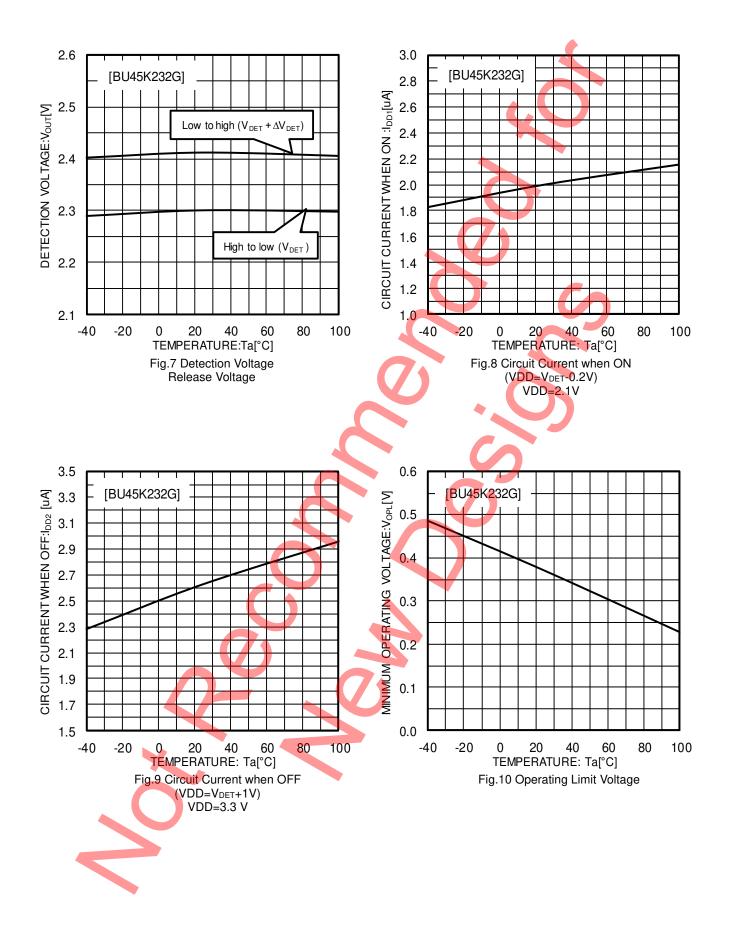
Block Diagrams



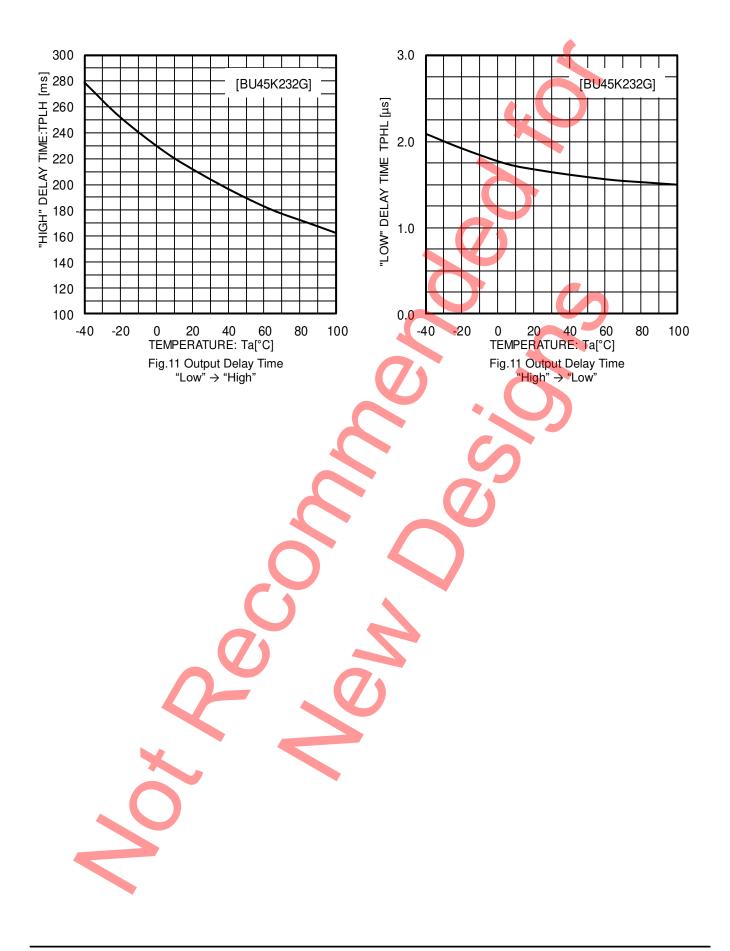
Typical Performance Curves



Typical Performance Curves - Continued



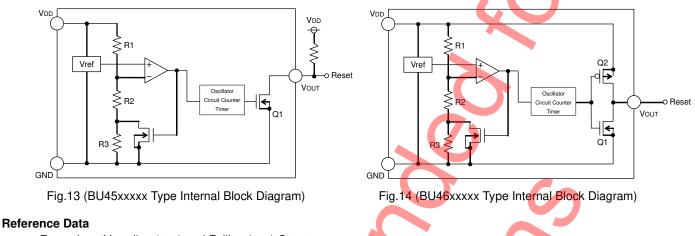
Typical Performance Curves - Continued



Application Information

Explanation of Operation

For both the open drain type (Fig.13) and the CMOS output type (Fig.14), the detection and release voltages are used as threshold voltages. When the voltage applied to the V_{DD} pins reaches the applicable threshold voltage, the V_{OUT} terminal voltage switches from either "High" to "Low" or from "Low" to "High". Because the BU45xxxxx series uses an open drain output type, it is necessary to connect a pull-up resistor to V_{DD} or another power supply if needed [The output "High" voltage (V_{OUT}) in this case becomes V_{DD} or the voltage of the other power supply].



Examples of Leading (tPLH) and Falling (tPHL) Output

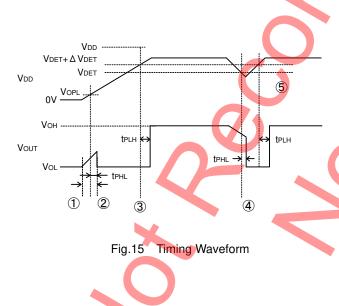
Part Number	tplh[ms]	tphl[µs]				
BU45K232G	208	1.4				
BU46K232G	208	1.4				
	VDD=1.8V→2.8V	VDD=2.8V→1.8V	7)			

*This data is for reference only.

The figures will vary with the application, so please confirm actual operating conditions before use.

Timing Waveform

Example: The following shows the relationship between the input voltages Vpp and the output voltage Vout when the input power supply voltage Vpp is made to sweep up and sweep down (the circuits are those in Fig. 13 and 14).



⁽¹⁾ When the power supply is turned on, the output is unstable from after over the operating limit voltage (V_{OPL}) until t_{PHL}. Therefore it is possible that the reset signal is not outputted when the rise time of V_{DD} is faster than t_{PHL}.

⁽²⁾ When V_{DD} is greater than V_{OPL} but less than the reset release voltage (V_{DET} + Δ V_{DET}), the output voltages will switch to Low.

If V_{DD} exceeds the reset release voltage ($V_{DET} + \Delta V_{DET}$), the counter timer start and V_{OUT} switches from L to H.

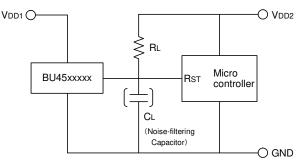
(4) If V_{DD} drops below the detection voltage (V_{DET}) when the power supply is powered down or when there is a power supply fluctuation, V_{OUT} switches to L (with a delay of t_{PHL}).

⁽⁵⁾ The potential difference between the detection voltage and the release voltage is known as the hysteresis width (ΔV_{DET}). The system is designed such that the output does not toggle with power supply fluctuations within this hysteresis width, thus, preventing malfunctions due to noise.

Timing may change depending on application and use. Please verify and confirm using practical applications.

Circuit Applications

1. Examples of a common power supply detection reset circuit.





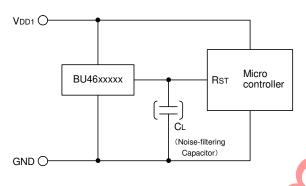


Fig.17 CMOS Output Type

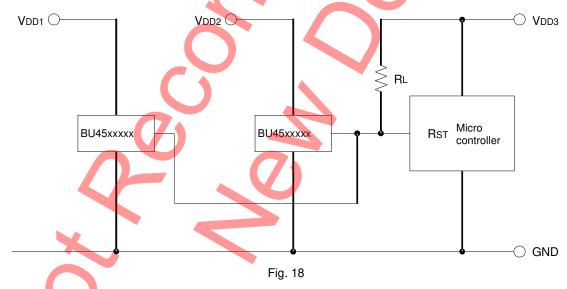
Application examples of BU45xxxxx series (Open Drain output type) and BU46xxxxx series (CMOS output type) are shown below.

CASE1: Power supply of microcontroller (VDD2) differs from the power supply of the reset detection (VDD1). Use an open drain output Type (BU45xxxxx series) device with a load resistance R_L as shown Fig.16.

CASE2: Power supply of the microcontroller (V_{DD1}) is same as the power supply of the reset detection (V_{DD1}). Use a CMOS output type (BU46xxxx) device or an open drain output type (BU45xxxx) with pull up resistor between the output and V_{DD1} . (As shown Fig.17)

When a capacitance C_L for noise filtering is connected to the V_{OUT} pin (the reset signal input terminal of the microcontroller), please take into account the waveform of the rise and fall of the output voltage (V_{OUT}).

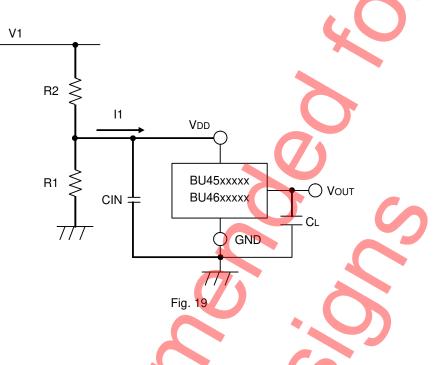
2. The following is an example of a circuit application in which an OR connection between two types of detection voltage resets the microcontroller.



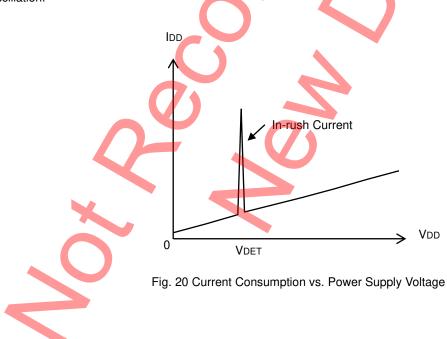
To reset the microcontroller when many independent power supplies are used in the system, OR connect an open drain output type (BU45xxxxx series) to the microcontroller's input with pull-up resistor to the supply voltage of the microcontroller (V_{DD3}) as shown in Fig. 18. By pulling-up to V_{DD3} , output "High" voltage of micro-controller power supply is possible.

Examples of the power supply with resistor dividers.

In applications wherein the power supply voltage of an IC comes from a resistor divider circuit, an in-rush current will flow into the circuit when the output level switches from "High" to "Low" or vice versa. In-rush current is a sudden surge of current that flows from the power supply (VDD) to ground (GND) as the output logic changes its state. This current flow may cause malfunction in the systems operation such as output oscillations, etc.



When an in-rush current (I1) flows into the circuit (Refer to Fig. 19) at the time when output switches from "Low" to "High", a voltage drop of I1×R2 (input resistor) will occur in the circuit causing the VDD supply voltage to decrease. When the VDD voltage drops below the detection voltage, the output will switch from "High" to "Low". While the output voltage is at "Low" condition, in-rush current will stop flowing and the voltage drop will be reduced. As a result, the output voltage will switches again from "Low" to "High" which causes an in-rush current and a voltage drop. This operation repeats and will result to oscillation.



Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. Unused Input Terminals

Input terminals of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input terminals should be connected to the power supply or ground line.

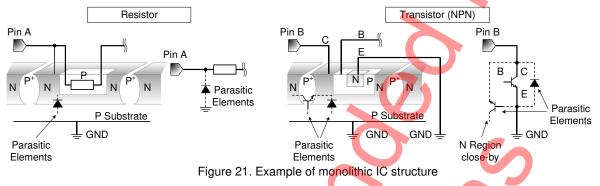


12. Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. Bypass Capacitor for Noise Rejection

To help reject noise, put a 1µF capacitor between VDD pin and GND and 1000pF capacitor between VOUT pin and GND. Be careful when using extremely big capacitor as transient response will be affected.

- 15. The VDD line impedance might cause oscillation because of the detection current.
- 16. A VDD to GND capacitor (as close connection as possible) should be used in high VDD line impedance condition.

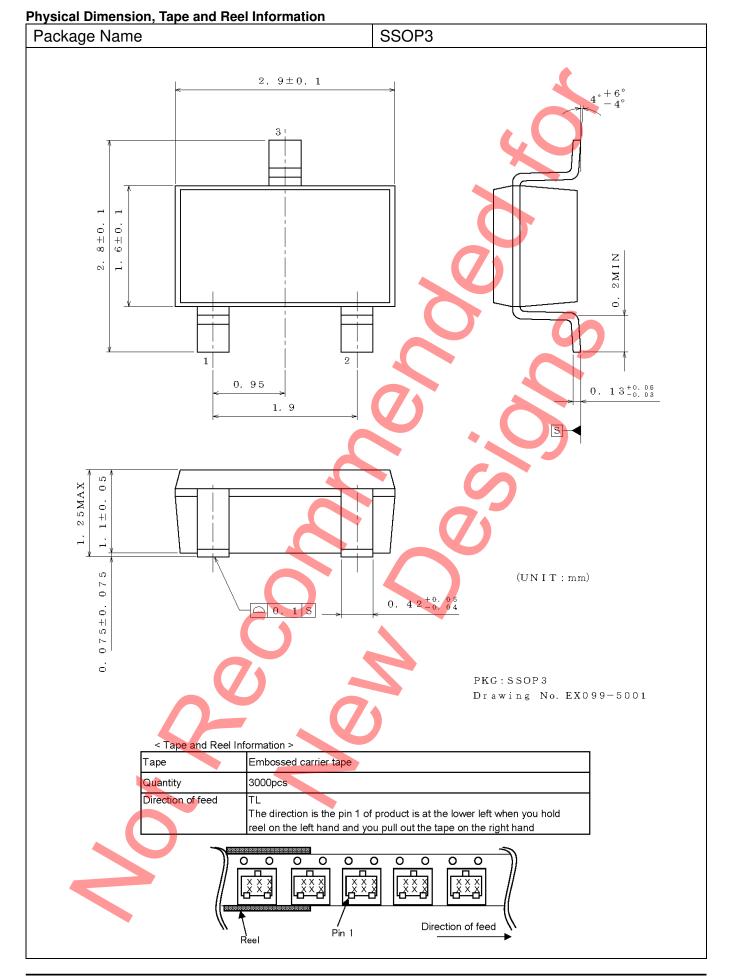
17. External Parameters

The recommended parameter range for RL is $50k\Omega$ to $470k\Omega$. There are many factors (board layout, etc) that can affect characteristics. Please verify and confirm using practical applications.

18. Lower than the mininum input voltage puts the VOUT in high impedance state, and it must be VDD in pull up (VDD) condition.

19. Power-on Reset Operation

- Please note that the power on reset output varies with the VDD rise time. Please verify the behavior in the actual operation.
- 20. This IC has extremely high impedance terminals. Small leak current due to the uncleanness of PCB surface might cause unexpected operations. Application values in these conditions should be selected carefully.



Revision History

Date
02.Sep.2021

Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	СКАСОШ
CLASSⅣ	CLASSII	CLASSⅢ	- CLASSII

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

Other Precaution

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.